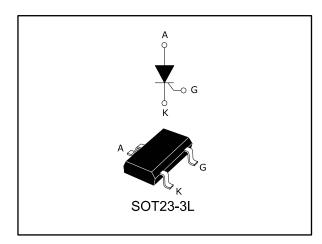


Sensitive high immunity 0.25 A SCR Thyristor

Datasheet - production data



Features

- I_{T(RMS)} 0.25 A
- Low 200 μA gate current
- High noise immunity 200 V/μs
- ECOPACK®2 compliant component

Applications

- Standby mode power supplies
- Smoke detectors
- DC 24/48 V proximity sensors
- Gate driver for large Thyristors
- Overvoltage crowbar protection
- Capacitive ignition circuit

Description

Thanks to highly sensitive triggering levels, the 0.25 A P0102BL SCR Thyristor is suitable for all applications where available gate current is limited. Its high immunity makes it ideal for high electric noise circuits.

The surface mount SOT23-3L package allows compact SMD based designs for automated manufacturing.

Table 1: Device summary

Symbol	Value	Unit
I _{T(RMS)}	0.25	Α
V _{DRM} /V _{RRM}	200	V
I _{GT}	200	μΑ
T _j max.	125	°C

Characteristics P0102BL

1 Characteristics

Table 2: Absolute maximum ratings (limiting values), Tj = 25 $^{\circ}$ C unless otherwise specified

Symbol	Parameter	Value	Unit		
I _{T(RMS)}	RMS on-state current (180 ° conduction angle)	T _{amb} = 36 °C	0.25	Α	
I _{T(AV)}	Average on-state current (180 ° conduction angle)	Tamb = 30 C	0.16	A	
l=o	Non repetitive surge peak on-state cur	urge peak on-state current $t_p = 8.3 \text{ ms}$ 7		7	_
$ T_{\rm SM} $ (T _j initial = 25 °C		$t_p = 10 \text{ ms}$	6	A	
l ² t	I ² t value for fusing	$t_p = 10 \text{ ms}$	0.18	A ² s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$ $f = 60 \text{ Hz}$		T _j = 125 °C	50	A/μs
V _{DRM} /V _{RRM}	Repetitive peak off-state voltage	T _j = 125 °C	200	V	
I _{GM}	Peak gate current $t_p = 20 \mu s$		T _j = 125 °C	0.5	Α
P _{G(AV)}	Average gate power dissipation	0.02	W		
T _{stg}	Storage junction temperature range	-40 to +150	°C		
Tj	Operating junction temperature	-40 to +125	°C		

Table 3: Electrical characteristics (Tj = 25 °C unless otherwise specified)

Symbol	Test conditions		Value	Unit	
lgт	Igt V 10 V P 140 C		Max.	200	μΑ
V _{GT}	$V_D = 12 \text{ V}, \text{ R}_L = 140 \Omega$			0.8	٧
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, R_{GK} = 1000 \Omega$ $T_j = 125 \text{ °C}$			0.1	٧
V_{RG}	$I_{RG} = 10 \mu A$			8	٧
lμ	I_T = 50 mA, R_{GK} = 1000 Ω			6	mA
IL	$I_G = 1.2 \text{ x } I_{GT}, R_{GK} = 1000 \Omega$			7	mA
dV/dt	$V_D = 67 \% V_{DRM}, R_{GK} = 1000 \Omega$ $T_j = 125 {}^{\circ}C$			200	V/µs

Table 4: Static characteristics

Symbol	Test conditions				Unit
V _{TM}	$I_{TM} = 0.4 \text{ A}, t_p = 380 \ \mu s$ $T_j = 25 \ ^{\circ}\text{C}$ M		Max.	1.7	V
V_{TO}	Threshold voltage	T _j = 125 °C	Max.	1	V
R_D	Dynamic resistance	T _j = 125 °C	Max.	1000	mΩ
1/1	V V .V D -4000 O	$T_j = 25 ^{\circ}C$	Max	1	
I _{DRM} /I _{RRM}	$V_D = V_{DRM}$; $V_R = V_{RRM}$, $R_{GK} = 1000 \Omega$	T _j = 125 °C	Max.	100	μΑ

Table 5: Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient (Mounted on FR4 with recommended pad layout)	400	°C/W



P0102BL Characteristics

1.1 Characteristics (curves)

0.00 0.02

0.04

0.06

Figure 1: Maximum average power dissipation versus average on-state current

Output

Discrete the state of t

Figure 2: Average and DC on-state current versus ambient temperature

0.30 IT(AV)(A)
0.25 0.20 0.15 0.10 0.05 0.00 0.05 0.00 0.25 50 75 100 125

Figure 3: Relative variation of thermal impedance junction to ambient versus pulse duration

0.08

0.10

0.14

0.16

0.18

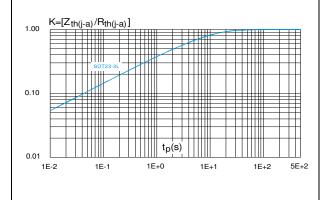


Figure 4: Gate trigger, holding, and latching currents with gate trigger voltage versus junction temperature

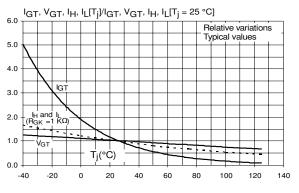


Figure 5: Relative variation of holding current versus gate-cathode resistance

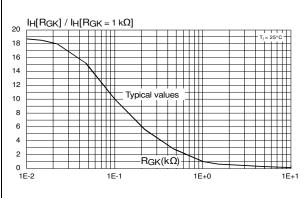
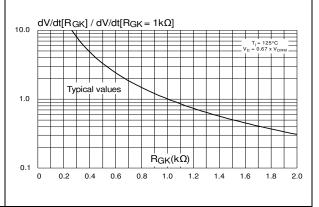


Figure 6: Relative variation of dV/dt immunity versus gate-cathode resistance



Characteristics P0102BL

Figure 7: Relative variation of dV/dt immunity versus gate-cathode capacitance

dV/dt[CGK] / dV/dt[PGK= 1kΩ, CGK = 0 F]

v₀ = 0.67 xV crost
T₁ = 125°C
Rex = 1kΩ

Typical values

C_{GK}(nF)

5

6

3

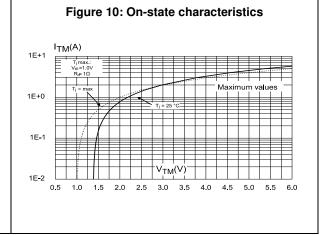
number of cycles

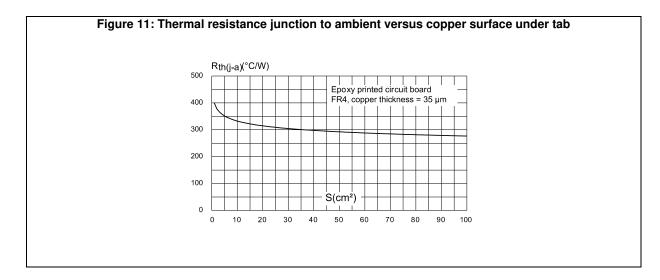
ITSM(A)

Non repetitive
T, initial = 25°C
Number of cycles

1 10 100 1000

Figure 8: Surge peak on-state current versus





P0102BL Package information

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Lead-free package
- Halogen free molding resin
- Epoxy meets UL94, V0

2.1 SOT23-3L package information

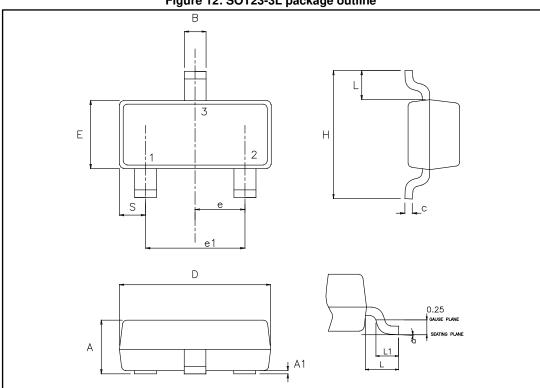


Figure 12: SOT23-3L package outline

This package drawing may slightly differ from the physical package. However, all the specified dimensions in the following table are guaranteed.

Table 6: SOT23-3L package mechanical data

	Dimensions					
Ref.	Millimeters		Inches ⁽¹⁾			
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.89		1.40	0.0350		0.0551
A1	0.00		0.10	0.0000		0.0039
В	0.30		0.51	0.0118		0.0201
С	0.085		0.18	0.0033		0.0071
D	2.75		3.04	0.1083		0.1197
е	0.85		1.05	0.0335		0.0413
e1	1.70		2.10	0.0669		0.0827
Е	1.20		1.75	0.0472		0.0689
Н	2.10		3.00	0.0827		0.1181
L		0.60			0.0236	
S	0.35		0.65	0.0138		0.256
L1	0.25		0.55	0.0098		0.0217
а	0°		8°	0°		8°

Notes:

0.97 0.48 0.95 0.99 2.89

Figure 13: SOT23-3L footprint in mm

This drawing may not be in scale; however, all the specified dimensions are guaranteed.

 $^{^{(1)}\}mbox{Dimension}$ in inches are given for reference only.

P0102BL Ordering information

3 Ordering information

Figure 14: Ordering information scheme

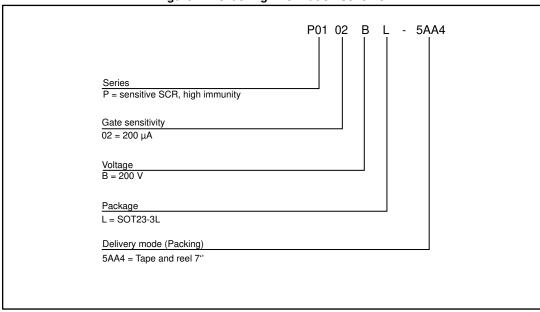


Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
P0102BL 5AA4	P2B	SOT23-3L	0.01 g	3000	Tape and reel 7"

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
05-Jun-2017	1	Initial release.
09-Aug-2017	2	Updated drawing in cover page.

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